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Electronic Filing System (EFS) Data  
Electronic Patent Application Submission  
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EFS ID: 61584  
Application ID: 10785160  
Title of Invention: TWIN EEPROM MEMORY TRANSISTORS  
WITH SUBSURFACE STEPPED FLOATING  
GATES  
First Named Inventor: Bohumil Lojek  
Domestic/Foreign Application: Domestic Application  
Filing Date: 2004-02-23  
Effective Receipt Date: 2004-05-26  
Submission Type: Information Disclosure Statement  
Filing Type:  
Confirmation number: 8504  
Attorney Docket Number: ATM-303



Total Fees Authorized:

Digital Certificate Holder: cn=Thomas Schneck,ou=Registered Attorneys,ou=Patent and Trademark  
Office,ou=Department of Commerce,o=U.S. Government,c=US  
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## TRANSMITTAL

Electronic Version v1.1  
Stylesheet Version v1.1.0

## Title of Invention

TWIN EEPROM MEMORY TRANSISTORS WITH SUBSURFACE STEPPED  
FLOATING GATES

Application Number: 10/785160   
Date: 2004-02-23  
First Named Applicant: Bohumil Lojek  
  
Confirmation Number: 8504  
Attorney Docket Number: ATM-303

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| Submitted by:                              | Elec. Sign.      | Sign. Capacity |
|--|------------------|----------------|
| Thomas Schneck<br>Registered Number: 24518 | /thomas schneck/ | Attorney       |

## Documents being submitted

us-ids

## Files

ATM303ids-usidst.xml

us-ids.dtd

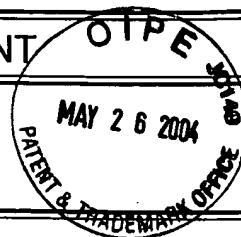
us-ids.xsl

## Comments

## ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0



## Title of Invention

TWIN EEPROM MEMORY TRANSISTORS WITH SUBSURFACE  
STEPPED FLOATING GATES

Application Number: 10/785160



Confirmation Number: 8504

First Named Applicant: Bohumil Lojek

Attorney Docket Number: ATM-303

Art Unit: 2811

Search string: ( 5424233 or 5917215 or 6043530 or 6323088 or 20020074583 ).pn.

## US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

| init | Cite.No. | Patent No. | Date       | Patentee        | Kind | Class | Subclass |
|------|----------|------------|------------|-----------------|------|-------|----------|
|      | 1        | 5424233    | 1995-06-13 | Yang et al.     | A1   | 437   | 43       |
|      | 2        | 5917215    | 1999-06-29 | Chuang et al.   | A1   | 257   | 321      |
|      | 3        | 6043530    | 2000-03-28 | Chang           | A1   | 257   | 320      |
|      | 4        | 6323088    | 2001-11-27 | Gonzalez et al. | A1   | 438   | 257      |

## US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

| init | Cite.No. | Pub. No.    | Date       | Applicant       | Kind | Class | Subclass |
|------|----------|-------------|------------|-----------------|------|-------|----------|
|      | 1        | 20020074583 | 2002-06-20 | Sugiyama et al. | A1   | 257   | 298      |

## Signature

Examiner Name

Date